

### Low-Voltage Input Boost Regulator for PIC<sup>®</sup> Microcontrollers

#### Features:

- Up to 96% Typical Efficiency
- 425 mA Typical Peak Input Current Limit:
  - $I_{OUT}$  > 50 mA @ 1.2V  $V_{IN},$  3.3V  $V_{OUT}$
  - $I_{OUT}$  > 175 mA @ 2.4V V<sub>IN</sub>, 3.3V V<sub>OUT</sub>
  - $I_{OUT}$  > 175 mA @ 3.3V V<sub>IN</sub> 5.0V V<sub>OUT</sub>
- Low Start-up Voltage: 0.65V, typical 3.3V V<sub>OUT</sub>
   @ 1 mA
- Low Operating Input Voltage: 0.35V, typical 3.3V<sub>OUT</sub> @ 1 mA
- Adjustable Output Voltage Range: 2.0V to 5.5V
- Maximum Input Voltage ≤ V<sub>OUT</sub> < 5.5V</li>
- Automatic PFM/PWM Operation (MCP1624)
- PWM-only Operation (MCP1623)
- 500 kHz PWM Frequency
- Low Device Quiescent Current: 19  $\mu A,$  typical PFM mode
- Internal Synchronous Rectifier
- Internal Compensation
- Inrush Current Limiting and Internal Soft-Start
- True Load Disconnect
- Shutdown Current (All States): < 1 µA</li>
- Low Noise, Anti-Ringing Control
- Overtemperature Protection
- SOT-23-6 and 2 x 3 DFN-8 Package

#### **Applications:**

 One, Two and Three Cell Alkaline and NiMH/NiCd Low-Power PIC<sup>®</sup> Microcontroller Applications

#### **General Description:**

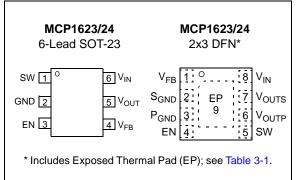
The MCP1623/24 is a compact, high-efficiency, fixed frequency, synchronous step-up DC-DC converter. It provides an easy-to-use power supply solution for PIC microcontroller applications powered by either one-cell, two-cell, or three-cell alkaline, NiCd, NiMH, one-cell Li-Ion or Li-Polymer batteries.

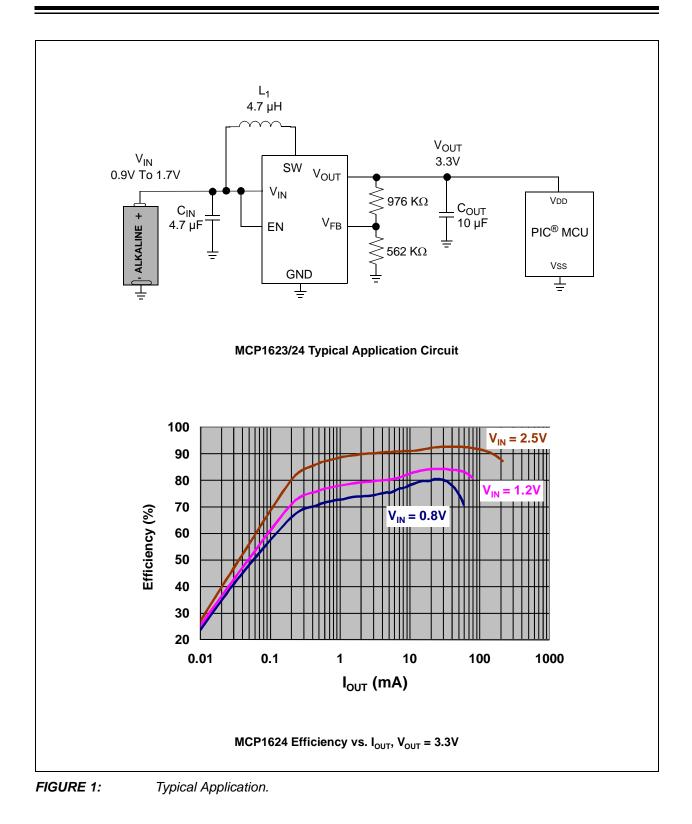
Low-voltage technology allows the regulator to start-up without high inrush current or output voltage overshoot from a low 0.65V input. High efficiency is accomplished by integrating the low resistance N-Channel Boost switch and synchronous P-Channel switch. All compensation and protection circuitry are integrated to minimize external components. For standby applications, the MCP1624 operates and consumes only 19  $\mu$ A while operating at no load. The MCP1623 device option is available that operates in PWM-only mode.

A "true" Load Disconnect mode provides input to output isolation while disabled (EN = GND) by removing the normal boost regulator diode path from input to output. This mode consumes less than 1  $\mu$ A of input current.

Output voltage is set by a small external resistor divider.

#### Packaging





#### 1.0 ELECTRICAL CHARACTERISTICS

#### Absolute Maximum Ratings †

EN, FB, V <sub>IN.</sub> V <sub>SW</sub> , V <sub>OUT</sub> - GND+6.5V
EN, FB < greater of $V_{OUT}$ or $V_{IN} > (GND - 0.3V)$
Output Short Circuit Current Continuous
Power Dissipation Internally Limited
Storage Temperature65°C to +150°C
Ambient Temp. with Power Applied40°C to +85°C
Operating Junction Temperature40°C to +125°C
ESD Protection On All Pins:
HBM3 kV
MM

**† Notice:** Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

#### **DC CHARACTERISTICS**

**Electrical Characteristics:** Unless otherwise indicated,  $V_{IN} = 1.2V$ ,  $C_{OUT} = C_{IN} = 10 \ \mu\text{F}$ ,  $L = 4.7 \ \mu\text{H}$ ,  $V_{OUT} = 3.3V$ ,  $I_{OUT} = 15 \ \text{mA}$ ,  $T_A = +25^{\circ}\text{C}$ . **Boldface** specifications apply over the  $T_A$  range of -40°C to +85°C.

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Input Characteristics	1	1				
Minimum Start-Up Voltage	V <sub>IN</sub>		0.65	0.8	V	Note 1
Minimum Input Voltage After Start-Up	V <sub>IN</sub>	—	0.35	—	V	Note 1
Output Voltage Adjust Range	V <sub>OUT</sub>	2.0		5.5	V	V <sub>OUT</sub> ≥ V <sub>IN</sub> ; Note 2
Maximum Output Current	I <sub>OUT</sub>	50	_	_	mA	1.5V V <sub>IN</sub> , 3.3V V <sub>OUT</sub>
Feedback Voltage	V <sub>FB</sub>	1.120	1.21	1.299	V	—
Feedback Input Bias Current	I <sub>VFB</sub>	—	10	—	pА	—
Quiescent Current – PFM mode	I <sub>QPFM</sub>	—	19	30	μA	Measured at $V_{OUT} = 4.0V$ ; EN = $V_{IN}$ , $I_{OUT} = 0$ mA; Note 3
Quiescent Current – PWM mode	I <sub>QPWM</sub>	—	220	—	μA	Measured at $V_{OUT}$ ; EN = $V_{IN}$ I <sub>OUT</sub> = 0 mA; Note 3
Quiescent Current – Shutdown	I <sub>Q</sub> SHDN	—	0.7	2.3	μA	V <sub>OUT</sub> = EN = GND; Includes N-Channel and P-Channel Switch Leakage
NMOS Switch Leakage	I <sub>NLK</sub>	—	0.3	1	μA	$V_{IN} = V_{SW} = 5V; V_{OUT} = 5.5V V_{EN} = V_{FB} = GND$
PMOS Switch Leakage	I <sub>PLK</sub>	—	0.05	0.2	μA	$V_{IN} = VS_W = GND;$ $V_{OUT} = 5.5V$
NMOS Switch ON Resistance	R <sub>DS(ON)N</sub>	—	0.6	_	Ω	V <sub>IN</sub> = 3.3V, I <sub>SW</sub> = 100 mA
PMOS Switch ON Resistance	R <sub>DS(ON)P</sub>	—	0.9	—	Ω	V <sub>IN</sub> = 3.3V, I <sub>SW</sub> = 100 mA

**Note 1:** 3.3 K $\Omega$  resistive load, 3.3V<sub>OUT</sub> (1 mA).

**2:** For  $V_{IN} > V_{OUT}$ ,  $V_{OUT}$  will not remain in regulation.

- **3:** I<sub>Q</sub> is measured from V<sub>OUT</sub>; V<sub>IN</sub> quiescent current will vary with boost ratio. V<sub>IN</sub> quiescent current can be estimated by: (I<sub>QPFM</sub> \* (V<sub>OUT</sub>/V<sub>IN</sub>)), (I<sub>QPWM</sub> \* (V<sub>OUT</sub>/V<sub>IN</sub>)).
- 4: 220 $\Omega$  resistive load, 3.3V<sub>OUT</sub> (15 mA).
- 5: Peak current limit determined by characterization, not production tested.

#### **DC CHARACTERISTICS (CONTINUED)**

Electrical Characteristics: Unless otherwise indicated,  $V_{IN}$  = 1.2V,  $C_{OUT}$  =  $C_{IN}$  = 10 µF, L = 4.7 µH,  $V_{OUT}$  = 3.3V,  $I_{OUT} = 15 \text{ mA}, T_A = +25^{\circ}\text{C}.$ 

Boldface specifications apply over the T <sub>A</sub> range of -40°C to +85°C.						
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
NMOS Peak Switch Current Limit	I <sub>N(MAX)</sub>	300	425		mA	Note 5
V <sub>OUT</sub> Accuracy	V <sub>OUT</sub> %	-7.4	—	+7.4	%	Includes Line and Load Regulation; $V_{IN} = 1.5V$ I <sub>OUT</sub> = 50 mA
Line Regulation	(ΔV <sub>OUT</sub> / V <sub>OUT</sub> ) / ΔV <sub>IN</sub>		0.01	—	%/V	$V_{IN} = 1.5V$ to 3V $I_{OUT} = 25$ mA
Load Regulation	ΔV <sub>OUT</sub> / V <sub>OUT</sub>		0.01	—	%	$I_{OUT}$ = 25 mA to 50 mA; V <sub>IN</sub> = 1.5V
Maximum Duty Cycle	DCMAX	_	90	—	%	
Switching Frequency	f <sub>SW</sub>	370	500	630	kHz	
EN Input Logic High	V <sub>IH</sub>	90		—	%of V <sub>IN</sub>	I <sub>OUT</sub> = 1 mA
EN Input Logic Low	V <sub>IL</sub>	_		20	%of V <sub>IN</sub>	I <sub>OUT</sub> = 1 mA
EN Input Leakage Current	I <sub>ENLK</sub>	-	0.005	—	μA	$V_{EN} = 5V$
Soft-start Time	t <sub>SS</sub>	—	750	—	μS	EN Low-to-High, 90% of V <sub>OUT</sub> ; <b>Note 4</b>
Thermal Shutdown Die Temperature	T <sub>SD</sub>		150		°C	
Die Temperature Hysteresis	T <sub>SDHYS</sub>	_	10	_	°C	

Note 1:  $3.3 \text{ K}\Omega$  resistive load,  $3.3 \text{V}_{\text{OUT}}$  (1 mA).

**2:** For  $V_{IN} > V_{OUT}$ ,  $V_{OUT}$  will not remain in regulation.

- 3: I<sub>Q</sub> is measured from V<sub>OUT</sub>; V<sub>IN</sub> quiescent current will vary with boost ratio. V<sub>IN</sub> quiescent current can be estimated by: (I<sub>QPFM</sub> \* (V<sub>OUT</sub>/V<sub>IN</sub>)), (I<sub>QPWM</sub> \* (V<sub>OUT</sub>/V<sub>IN</sub>)).
- 4: 220 $\Omega$  resistive load, 3.3V<sub>OUT</sub> (15 mA).
- 5: Peak current limit determined by characterization, not production tested.

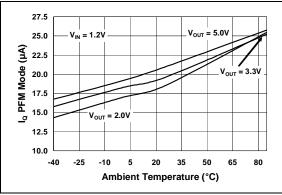
#### **TEMPERATURE SPECIFICATIONS**

Electrical Specifications:						
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Operating Junction Temperature Range	TJ	-40	—	+125	°C	Steady State
Storage Temperature Range	T <sub>A</sub>	-65	—	+150	°C	
Maximum Junction Temperature	ТJ	—	—	+150	°C	Transient
Package Thermal Resistance						•
Thermal Resistance, 5L-TSOT23	$\theta_{JA}$	_	192	—	°C/W	EIA/JESD51-3 Standard

#### 2.0 TYPICAL PERFORMANCE CURVES

**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated,  $V_{IN} = EN = 1.2V$ ,  $C_{OUT} = C_{IN} = 10 \ \mu$ F,  $L = 4.7 \ \mu$ H,  $V_{OUT} = 3.3V$ ,  $I_{LOAD} = 15 \ m$ A,  $T_A = +25^{\circ}$ C.



**FIGURE 2-1:**  $V_{OUT} I_Q$  vs. Ambient Temperature in PFM Mode.

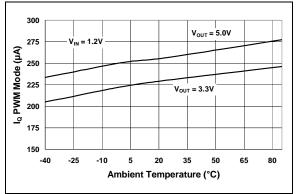
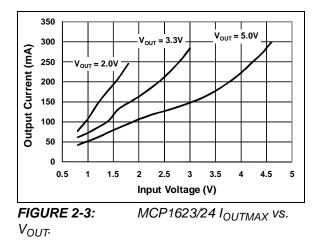
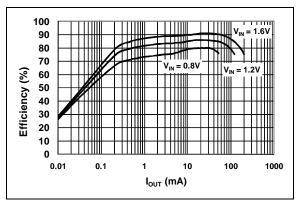
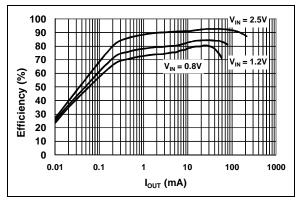


FIGURE 2-2: V<sub>OUT</sub> I<sub>Q</sub> vs. Ambient Temperature in PWM Mode.

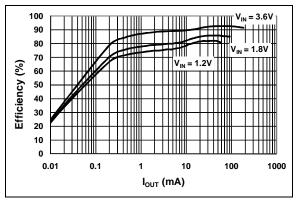




**FIGURE 2-4:** MCP1624 Efficiency vs.  $I_{OUT}$ ,  $V_{OUT} = 2.0V$ .

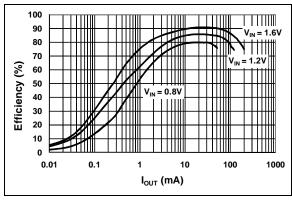


**FIGURE 2-5:** MCP1624 Efficiency vs.  $I_{OUT}$ ,  $V_{OUT} = 3.3V$ .

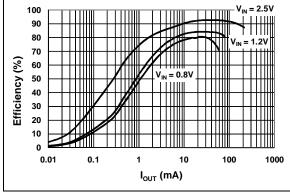


**FIGURE 2-6:** MCP1624 Efficiency vs.  $I_{OUT}$ ,  $V_{OUT} = 5.0V$ .

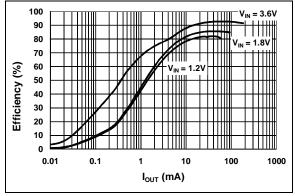
**Note:** Unless otherwise indicated,  $V_{IN} = EN = 1.2V$ ,  $C_{OUT} = C_{IN} = 10 \ \mu\text{F}$ ,  $L = 4.7 \ \mu\text{H}$ ,  $V_{OUT} = 3.3V$ ,  $I_{LOAD} = 15 \ \text{mA}$ ,  $T_A = +25^{\circ}\text{C}$ .



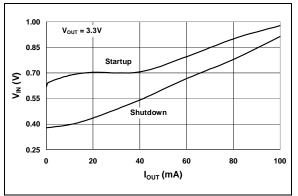




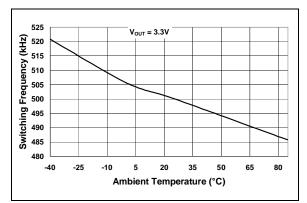




**FIGURE 2-9:** MCP1623 Efficiency vs.  $I_{OUT}$ ,  $V_{OUT} = 5.0V$ .



**FIGURE 2-10:** Minimum Start-up and Shutdown  $V_{IN}$  into Resistive Load vs.  $I_{OUT}$ .



**FIGURE 2-11:** F<sub>OSC</sub> vs. Ambient Temperature.

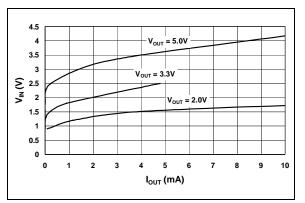


FIGURE 2-12: MCP1623 PWM Pulse Skipping Mode Threshold vs. I<sub>OUT</sub>.

Note: Unless otherwise indicated,  $V_{IN}$  = EN = 1.2V,  $C_{OUT}$  =  $C_{IN}$  = 10 µF, L = 4.7 µH,  $V_{OUT}$  = 3.3V,  $I_{LOAD}$  = 15 mA,  $T_A$  = +25°C.

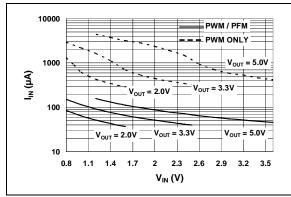


FIGURE 2-13: Input No Load Current vs. V<sub>IN</sub>.

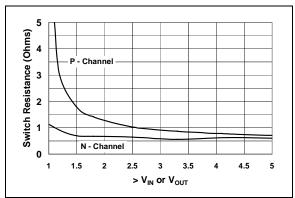


FIGURE 2-14:N-Channel and P-Channel $R_{DSON}$  vs. > of  $V_{IN}$  or  $V_{OUT}$ .

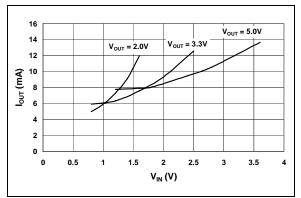
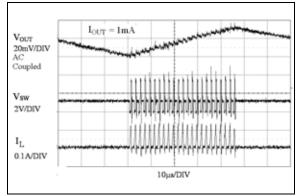
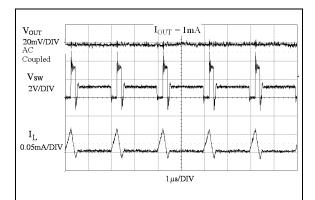


FIGURE 2-15: PFM/PWM Threshold Current vs. V<sub>IN</sub>.



**FIGURE 2-16:** MCP1624 3.3V V<sub>OUT</sub> PFM Mode Waveforms.



**FIGURE 2-17:** MCP1623 3.3V V<sub>OUT</sub> PWM Mode Waveforms.

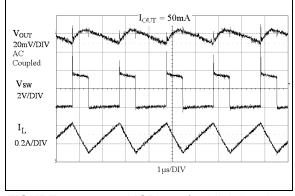


FIGURE 2-18: MCP1623/24 High Load Waveforms.

Note: Unless otherwise indicated,  $V_{IN}$  = EN = 1.2V,  $C_{OUT}$  =  $C_{IN}$  = 10 µF, L = 4.7 µH,  $V_{OUT}$  = 3.3V,  $I_{LOAD}$  = 15 mA,  $T_A$  = +25°C.

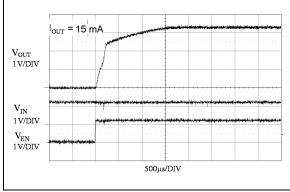
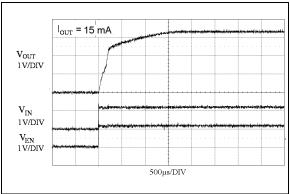
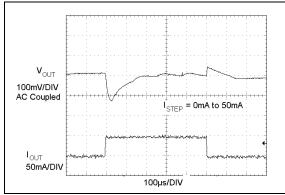


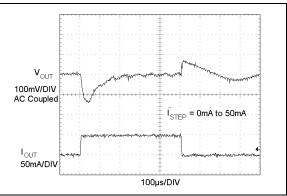
FIGURE 2-19: 3.3V Start-up After Enable.



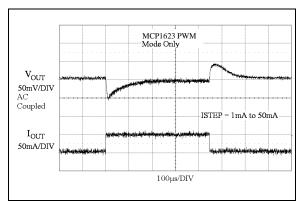
**FIGURE 2-20:** 3.3V Start-up when  $V_{IN} = V_{ENABLE}$ .



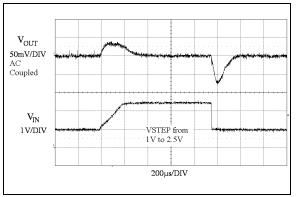
**FIGURE 2-21:** MCP1624 3.3V V<sub>OUT</sub> Load Transient Waveforms.



**FIGURE 2-22:** MCP1623 3.3V V<sub>OUT</sub> Load Transient Waveforms.



**FIGURE 2-23:** MCP1623 2.0V V<sub>OUT</sub> Load Transient Waveforms.



**FIGURE 2-24:** 3.3V V<sub>OUT</sub> Line Transient Waveforms.

#### 3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

MCP1623/24           SOT23         2x3 DFN		623/24	Description
		2x3 DFN	— Description
SW	1	5	Switch Node, Boost Inductor Input Pin
GND	2	—	Ground Pin
EN	3	4	Enable Control Input Pin
FB	4	1	Feedback Voltage Pin
V <sub>OUT</sub>	5	—	Output Voltage Pin
V <sub>IN</sub>	6	8	Input Voltage Pin
S <sub>GND</sub>	_	2	Signal Ground Pin
P <sub>GND</sub>	—	3	Power Ground Pin
V <sub>OUTS</sub>	_	7	Output Voltage Sense Pin
V <sub>OUTP</sub>	—	6	Output Voltage Power Pin
EP	_	9	Exposed Thermal Pad (EP); must be connected to V <sub>SS.</sub>

#### TABLE 3-1: PIN FUNCTION TABLE

#### 3.1 Switch Node Pin (SW)

Connect the inductor from the input voltage to the SW pin. The SW pin carries inductor current and can be as high as 425 mA peak. The integrated N-Channel switch drain and integrated P-Channel switch source are internally connected at the SW node.

#### 3.2 Ground Pin (GND)

The ground or return pin is used for circuit ground connection. Length of trace from input cap return, output cap return and GND pin should be made as short as possible to minimize noise on the GND pin.

#### 3.3 Enable Pin (EN)

The EN pin is a logic-level input used to enable or disable device switching and lower quiescent current while disabled. A logic high (>90% of  $V_{IN}$ ) will enable the regulator output. A logic low (<20% of  $V_{IN}$ ) will ensure that the regulator is disabled.

#### 3.4 Feedback Voltage Pin (FB)

The FB pin is used to provide output voltage regulation by using a resistor divider. The FB voltage will be 1.21V typical with the output voltage in regulation.

#### 3.5 Output Voltage Pin (V<sub>OUT</sub>)

The output voltage pin connects the integrated P-Channel MOSFET to the output capacitor. The FB voltage divider is also connected to the  $V_{OUT}$  pin for voltage regulation.

#### 3.6 Power Supply Input Voltage Pin (V<sub>IN</sub>)

Connect the input voltage source to V\_{IN}. The input source should be decoupled to GND with a 4.7  $\mu F$  minimum capacitor.

#### 3.7 Signal Ground Pin (S<sub>GND</sub>)

The signal ground pin is used as a return for the integrated V<sub>REF</sub> and error amplifier. In the 2x3 DFN package, the S<sub>GND</sub> and power ground (P<sub>GND</sub>) pins are connected externally.

#### 3.8 Power Ground Pin (P<sub>GND</sub>)

The power ground pin is used as a return for the high-current N-Channel switch. In the 2x3 DFN package, the  $P_{GND}$  and signal ground (S<sub>GND</sub>) pins are connected externally.

#### 3.9 Output Voltage Sense Pin (V<sub>OUTS</sub>)

The output voltage sense pin connects the regulated output voltage to the internal bias circuits. In the 2x3 DFN package,  $V_{OUTS}$  and  $V_{OUTP}$  are connected externally.

#### 3.10 Output Voltage Power Pin (V<sub>OUTP</sub>)

The output voltage power pin connects the output voltage to the switch node. High current flows through the integrated P-Channel and out of this pin to the output capacitor and output. In the 2x3 DFN package,  $V_{OUTS}$  and  $V_{OUTP}$  are connected externally.

#### 3.11 Exposed Thermal Pad (EP)

There is an internal electrical connection between the Exposed Thermal Pad (EP) and the  $V_{SS}$  pin; they must be connected to the same potential on the Printed Circuit Board (PCB).

#### 4.0 DETAILED DESCRIPTION

#### 4.1 Device Option Overview

The MCP1623/24 family of devices is capable of low start-up voltage and delivers high efficiency over a wide load range for single cell, two cell, three cell alkaline, NiMH, NiCd and single cell Li-Ion battery inputs. A high level of integration lowers total system cost, eases implementation and reduces board area. The devices feature low start-up voltage, adjustable output voltage, PWM/PFM mode operation, low  $I_Q$ , integrated synchronous switch, internal compensation, low noise anti-ring control, inrush current limit and soft start. There is one feature option for the MCP1623/24 family: PWM/PFM mode or PWM mode only.

#### 4.1.1 PWM/PFM MODE OPTION

The MCP1624 devices use an automatic switchover from PWM to PFM mode for light load conditions to maximize efficiency over a wide range of output current. During PFM mode, higher peak current is used to pump the output up to the threshold limit. While operating in PFM or PWM mode, the P-Channel switch is used as a synchronous rectifier, turning off when the inductor current reaches 0 mA to maximize efficiency. In PFM mode, a comparator is used to terminate switching when the output voltage reaches the upper threshold limit. Once switching has terminated, the output voltage will decay or coast down. During this period, very low  $I_{\Omega}$  is consumed from the device and input source, which keeps power efficiency high at light load. The disadvantages of PWM/PFM mode are higher output ripple voltage and variable PFM mode frequency. The PFM mode frequency is a function of input voltage, output voltage and load. While in PFM mode, the boost converter pumps the output up at a switching frequency of 500 kHz.

#### 4.1.2 PWM MODE ONLY OPTION

The MCP1623 devices disable PFM mode switching, and operate only in PWM mode over the entire load range. During periods of light load operation, the MCP1623 continues to operate at a constant 500 kHz switching frequency, keeping the output ripple voltage lower than PFM mode. During PWM-only mode, the MCP1623 P-Channel switch acts as a synchronous rectifier by turning off to prevent reverse current flow from the output cap back to the input in order to keep efficiency high. For noise immunity, the N-Channel MOSFET current sense is blanked for approximately 100 ns. With a typical minimum duty cycle of 100 ns, the MCP1623 continues to switch at a constant frequency under light load conditions. Figure 2-12 represents the input voltage versus load current for the pulse-skipping threshold in PWM-only mode. At lighter loads, the MCP1623 device begins to skip pulses.

Part Number	PWM/PFM	PWM
MCP1624	Х	
MCP1623		Х

#### 4.2 Functional Description

The MCP1623/24 is a compact, high-efficiency, fixed frequency, step-up DC-DC converter that provides an easy-to-use power supply solution for PIC microcontroller applications powered by either one-cell, two-cell, or three-cell alkaline, NiCd, or NiMH, or one-cell Li-Ion or Li-Polymer batteries.

Figure 4-1 depicts the functional block diagram of the MCP1623/24.

#### 4.2.1 LOW-VOLTAGE START-UP

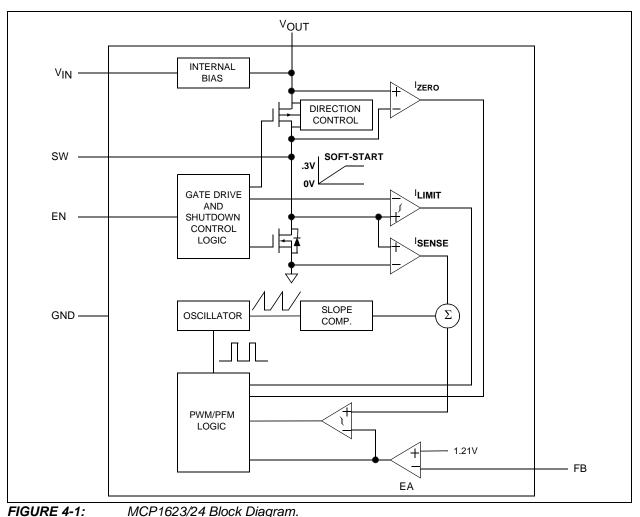
The MCP1623/24 is capable of starting from a low input voltage. Start-up voltage is typically 0.65V for a 3.3V output and 1 mA resistive load.

When enabled, the internal start-up logic turns the rectifying P-Channel switch on until the output capacitor is charged to a value close to the input voltage. The rectifying switch is current limited during this time. After charging the output capacitor to the input voltage, the device starts switching. If the input voltage is below 1.6V, the device runs open-loop with a fixed duty cycle of 70% until the output reaches 1.6V.

During this time, the boost switch current is limited to 50% of its nominal value. Once the output voltage reaches 1.6V, normal closed-loop PWM operation is initiated.

The MCP1623/24 charges an internal capacitor with a very weak current source. The voltage on this capacitor, in turn, slowly ramps the current limit of the boost switch to its nominal value. The soft-start capacitor is completely discharged in the event of a commanded shutdown or a thermal shutdown.

There is no undervoltage lockout feature for the MCP1623/24. The device will start-up at the lowest possible voltage and run down to the lowest possible voltage. For typical battery applications, this may result in "motor-boating" for deeply discharged batteries.



#### 4.2.2 PWM MODE OPERATION

In normal PWM operation, the MCP1623/24 operates as a fixed frequency, synchronous boost converter. The switching frequency is internally maintained with a oscillator typically set to 500 kHz. The MCP1623 device will operate in PWM-only mode even during periods of light load operation. By operating in PWMonly mode, the output ripple remains low and the frequency is constant. Operating in fixed PWM mode results in lower efficiency during light load operation (when compared to PFM mode (MCP1624).

Lossless current sensing converts the peak current signal to a voltage to sum with the internal slope compensation. This summed signal is compared to the voltage error amplifier output to provide a peak current control command for the PWM signal. The slope compensation is adaptive to the input and output voltage. Therefore, the converter provides the proper amount of slope compensation to ensure stability, but is not excessive, which causes a loss of phase margin. The peak current limit is set to 425 mA typical.

#### 4.2.3 PFM MODE OPERATION

The MCP1624 device is capable of operating in normal PWM mode and PFM mode to maintain high efficiency at all loads. In PFM mode, the output ripple has a variable frequency component that changes with the input voltage and output current. With no load, the quiescent current draw from the output is typically 19  $\mu$ A. The PFM mode can be disabled in selected device options.

PFM operation is initiated if the output load current falls below an internally programmed threshold. The output voltage is continuously monitored. When the output voltage drops below its nominal value, PFM operation pulses one or several times to bring the output back into regulation. If the output load current rises above the upper threshold, the MCP1624 transitions smoothly into PWM mode.

#### 4.2.4 ADJUSTABLE OUTPUT VOLTAGE

The MCP1623/24 output voltage is adjustable with a resistor divider over a 2.0V minimum to 5.5V maximum range. High value resistors are recommended to minimize quiescent current to keep efficiency high at light loads.

#### 4.2.5 ENABLE/OUTPUT DISCONNECT

The enable pin is used to turn the boost converter on and off. The enable threshold voltage varies with input voltage. To enable the boost converter, the EN voltage level must be greater than 90% of the V<sub>IN</sub> voltage. To disable the boost converter, the EN voltage must be less than 20% of the V<sub>IN</sub> voltage.

The MCP1623/24 devices incorporate a true output disconnect feature. With the EN pin pulled low, the output of the MCP1623/24 is isolated or disconnected from the input by turning off the integrated P-Channel switch and removing the switch bulk diode connection. This removes the DC path typical in boost converters, which allows the output to be disconnected from the input. During this mode, less than 1  $\mu$ A of current is consumed from the input (battery). True output disconnect does not discharge the output; the output voltage is held up by the external C<sub>OUT</sub> capacitance.

#### 4.2.6 INTERNAL BIAS

The MCP1623/24 gets its start-up bias from V<sub>IN</sub>. Once the output exceeds the input, bias comes from the output. Therefore, once started, operation is completely independent of V<sub>IN</sub>. Operation is only limited by the output power level and the input source series resistance. Once started, the output will remain in regulation down to 0.35V typical with 1 mA output current for low source impedance inputs.

#### 4.2.7 INTERNAL COMPENSATION

The error amplifier, with its associated compensation network, completes the closed loop system by comparing the output voltage to a reference at the input of the error amplifier, and feeding the amplified and inverted signal to the control input of the inner current loop. The compensation network provides phase leads and lags at appropriate frequencies to cancel excessive phase lags and leads of the power circuit. All necessary compensation components and slope compensation are integrated.

#### 4.2.8 SHORT CIRCUIT PROTECTION

Unlike most boost converters, the MCP1623/24 allows its output to be shorted during normal operation. The internal current limit and overtemperature protection limit excessive stress and protect the device during periods of short circuit, overcurrent and overtemperature.

#### 4.2.9 LOW NOISE OPERATION

The MCP1623/24 integrates a low noise anti-ring switch that damps the oscillations typically observed at the switch node of a boost converter when operating in the Discontinuous Inductor Current mode. This removes the high frequency radiated noise.

#### 4.2.10 OVERTEMPERATURE PROTECTION

Overtemperature protection circuitry is integrated in the MCP1623/24. This circuitry monitors the device junction temperature and shuts the device off if the junction temperature exceeds the typical +150°C threshold. If this threshold is exceeded, the device will automatically restart once the junction temperature drops by 10°C. The soft start is reset during an overtemperature condition.

#### 5.0 APPLICATION INFORMATION

#### 5.1 Typical Applications

The MCP1623/24 synchronous boost regulator operates over a wide input voltage and output voltage range. The power efficiency is high for several decades of load range. Output current capability increases with input voltage and decreases with increasing output voltage. The maximum output current is based on the N-Channel peak current limit. Typical characterization curves in this data sheet are presented to display the typical output current capability.

#### 5.2 Adjustable Output Voltage Calculations

To calculate the resistor divider values for the MCP1623/24, the following equation can be used. Where  $R_{TOP}$  is connected to  $V_{OUT}$ ,  $R_{BOT}$  is connected to GND and both are connected to the FB input pin.

#### **EQUATION 5-1:**

$$R_{TOP} = R_{BOT} \times \left(\frac{V_{OUT}}{V_{FB}} - 1\right)$$

Example A:

 $V_{OUT} = 3.3V$ 

V<sub>FB</sub> = 1.21V

 $R_{BOT} = 309 \text{ k}\Omega$ 

 $R_{TOP} = 533.7 \text{ k}\Omega \text{ (Standard Value = 536 k}\Omega \text{)}$ 

Example B:

 $V_{OUT} = 5.0V$ 

V<sub>FB</sub> = 1.21V

 $R_{BOT} = 309 \text{ k}\Omega$ 

 $R_{TOP} = 967.9 \text{ k}\Omega \text{ (Standard Value = 976 k}\Omega \text{)}$ 

There are some potential issues with higher value resistors. For small surface mount resistors, environment contamination can create leakage paths that significantly change the resistor divider that effect the output voltage. The FB input leakage current can also impact the divider and change the output voltage tolerance.

#### 5.3 Input Capacitor Selection

The boost input current is smoothed by the boost inductor reducing the amount of filtering necessary at the input. Some capacitance is recommended to provide decoupling from the source. Low ESR X5R or X7R are well suited since they have a low temperature coefficient and small size. For most applications, 4.7  $\mu$ F of capacitance is sufficient at the input. For high power applications that have high source impedance or long leads, connecting the battery to the input 10  $\mu$ F of capacitance is recommended. Additional input capacitance can be added to provide a stable input voltage.

 Table 5-1 contains the recommended range for the input capacitor value.

#### 5.4 Output Capacitor Selection

The output capacitor helps provide a stable output voltage during sudden load transients and reduces the output voltage ripple. As with the input capacitor, X5R and X7R ceramic capacitors are well suited for this application.

The MCP1623/24 is internally compensated so output capacitance range is limited. See Table 5-1 for the recommended output capacitor range.

While the N-Channel switch is on, the output current is supplied by the output capacitor  $C_{OUT}$ . The amount of output capacitance and equivalent series resistance will have a significant effect on the output ripple voltage. While  $C_{OUT}$  provides load current, a voltage drop also appears across its internal ESR that results in ripple voltage.

#### **EQUATION 5-2:**

$$I_{OUT} = C_{OUT} \times \left(\frac{dV}{dt}\right)$$

Where dV represents the ripple voltage and dt represents the ON time of the N-Channel switch (D \* 1/  $F_{SW}).$ 

 Table 5-1 contains the recommended range for the input and output capacitor value.

#### TABLE 5-1:CAPACITOR VALUE RANGE

	C <sub>IN</sub>	C <sub>OUT</sub>
Min	4.7 µF	10 µF
Max	none	100 µF

#### 5.5 Inductor Selection

The MCP1623/24 is designed to be used with small surface mount inductors; the inductance value can range from 2.2  $\mu$ H to 10  $\mu$ H. An inductance value of 4.7  $\mu$ H is recommended to achieve a good balance between inductor size, converter load transient response and minimized noise.

TABLE 5-2:	MCP1623/24 RECOMMENDED
	INDUCTORS

Part Number	Value (µH)	DCR Ω (typ)	I <sub>SAT</sub> (A)	Size WxLxH (mm)	
Coilcraft <sup>®</sup>					
ME3220	4.7	0.190	1.5	2.5x3.2x2.0	
LPS3015	4.7	0.200	1.2	3.0x3.0x1.5	
EPL3012	4.7	0.165	1.0	3.0x3.0x1.3	
XPL2010	4.7	0.336	0.75	1.9x2.0x1.0	
Coiltronics	®				
SD3110	4.7	0.285	0.68	3.1x3.1x1.0	
SD3112	4.7	0.246	0.80	3.1x3.1x1.2	
SD3114	4.7	0.251	1.14	3.1x3.1x1.4	
Part Number	Value (µH)	DCR Ω (max)	I <sub>SAT</sub> (A)	Size WxLxH (mm)	
Wurth Elek	tronik <sup>®</sup>				
WE-TPC Type TH	4.7	0.200	0.8	2.8x2.8x1.35	
WE-TPC Type S	4.7	0.105	0.90	3.8x3.8x1.65	
WE-TPC Type M	4.7	0.082	1.65	4.8x4.8x1.8	
Part Number	Value (µH)	DCR Ω (max)	I <sub>SAT</sub> (A)	Size WxLxH (mm)	
Sumida <sup>®</sup>	•	•			
CMH23	4.7	0.537	0.70	2.3x2.3x1.0	
CMD4D06	4.7	0.216	0.75	3.5x4.3x0.8	
CDRH4D	4.7	0.09	0.800	4.6x4.6x1.5	
<b>EPCOS<sup>®</sup></b>	EPCOS <sup>®</sup>				
B82462A2 472M000	4.7	0.084	2.00	6.0x6.0x2.5	
B82462G4 472M	4.7	0.04	1.8	6.3x6.3x3.0	

Several parameters are used to select the correct inductor: maximum rated current, saturation current and copper resistance (ESR). For boost converters, the inductor current can be much higher than the output current. The lower the inductor ESR, the higher the efficiency of the converter, a common trade-off in size versus efficiency. Peak current is the maximum or limit, and saturation current typically specifies a point at which the inductance has rolled off a percentage of the rated value. This can range from a 20% to 40% reduction in inductance. As inductance rolls off, the inductor ripple current increases as does the peak switch current. It is important to keep the inductance from rolling off too much, causing switch current to reach the peak limit.

#### 5.6 Thermal Calculations

By calculating the power dissipation and applying the package thermal resistance,  $(\theta_{JA})$ , the junction temperature is estimated. The maximum continuous junction temperature rating for the MCP1623/24 is +125°C.

To quickly estimate the internal power dissipation for the switching boost regulator, an empirical calculation using measured efficiency can be used. Given the measured efficiency, the internal power dissipation is estimated by Equation 5-3.

#### **EQUATION 5-3:**

$$\left(\frac{V_{OUT} \times I_{OUT}}{Efficiency}\right) - (V_{OUT} \times I_{OUT}) = P_{Dis}$$

The difference between the first term, input power, and the second term, power delivered, is the internal MCP1623/24 power dissipation. This is an estimate assuming that most of the power lost is internal to the MCP1623/24 and not  $C_{IN}$ ,  $C_{OUT}$  and the inductor. There is some percentage of power lost in the boost inductor, with very little loss in the input and output capacitors. For a more accurate estimation of internal power dissipation, subtract the  $I_{INRMS}^{2*}L_{ESR}$  power dissipation.

#### 5.7 PCB Layout Information

Good printed circuit board layout techniques are important to any switching circuitry and switching power supplies are no different. When wiring the switching high current paths, short and wide traces should be used. Therefore, it is important that the input and output capacitors be placed as close as possible to the MCP1623/24 to minimize the loop area.

The feedback resistors and feedback signal should be routed away from the switching node and the switching current loop. When possible, ground planes and traces should be used to help shield the feedback signal and minimize noise and magnetic interference.

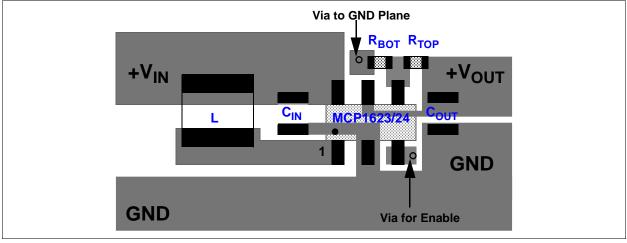


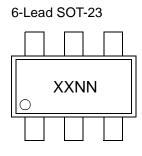
FIGURE 5-1:

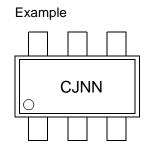
MCP1623/24 SOT-23-6 Recommended Layout.

NOTES:

#### 6.0 PACKAGING INFORMATION

#### 6.1 Package Marking Information (Not to Scale)





Package Marking					
MCP1623 HUNN					
MCP1624 CJNN					

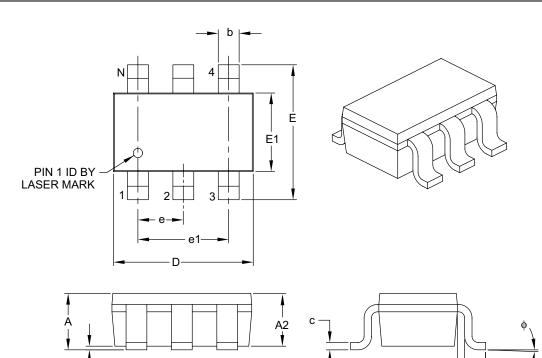


Package Marking					
MCP1623	AKH				
MCP1624 ALH					

Legend	: XXX Y YY WW NNN @3 *	Customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.
	be carrie	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for customer-specific information.

#### 6-Lead Plastic Small Outline Transistor (CHY) [SOT-23]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		MILLIMETERS		
	Dimension Limits	MIN	NOM	MAX	
Number of Pins	N	6			
Pitch	e		0.95 BSC		
Outside Lead Pitch	e1		1.90 BSC		
Overall Height	A	0.90	-	1.45	
Molded Package Thickness	A2	0.89	-	1.30	
Standoff	A1	0.00	-	0.15	
Overall Width	E	2.20	-	3.20	
Molded Package Width	E1	1.30	-	1.80	
Overall Length	D	2.70	-	3.10	
Foot Length	L	0.10	-	0.60	
Footprint	L1	0.35	-	0.80	
Foot Angle	φ	0°	-	30°	
Lead Thickness	С	0.08	-	0.26	
Lead Width	b	0.20	-	0.51	

#### Notes:

1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127 mm per side.

2. Dimensioning and tolerancing per ASME Y14.5M.

A1

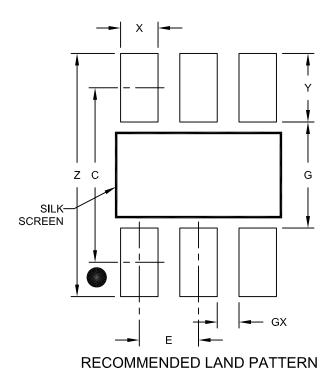
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-028B

L1

#### 6-Lead Plastic Small Outline Transistor (CHY) [SOT-23]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	Е	0.95 BSC		
Contact Pad Spacing	С		2.80	
Contact Pad Width (X6)	Х			0.60
Contact Pad Length (X6)	Y			1.10
Distance Between Pads	G	1.70		
Distance Between Pads	GX	0.35		
Overall Width	Z			3.90

Notes:

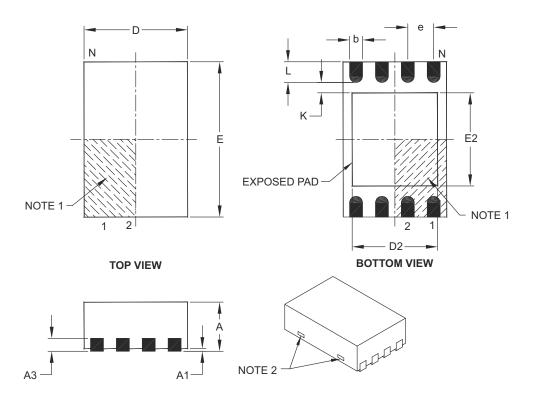
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2028A

#### 8-Lead Plastic Dual Flat, No Lead Package (MC) – 2x3x0.9 mm Body [DFN]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units MILLIMETERS			5
	MIN	NOM	MAX	
Number of Pins	N	8		
Pitch	e	0.50 BSC		
Overall Height	A	0.80 0.90 1.00		
Standoff	A1	0.00 0.02 0.05		
Contact Thickness	A3	0.20 REF		
Overall Length	D	2.00 BSC		
Overall Width	E	3.00 BSC		
Exposed Pad Length	D2	1.30	-	1.55
Exposed Pad Width	E2	1.50	-	1.75
Contact Width	b	0.20 0.25 0.30		
Contact Length	L	0.30 0.40 0.50		
Contact-to-Exposed Pad	K	0.20	-	-

#### Notes:

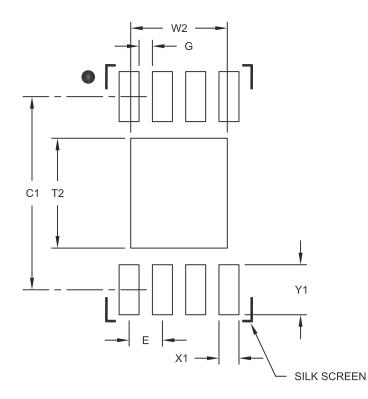
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package may have one or more exposed tie bars at ends.
- 3. Package is saw singulated.
- 4. Dimensioning and tolerancing per ASME Y14.5M.
  - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-123C

#### 8-Lead Plastic Dual Flat, No Lead Package (MC) – 2x3x0.9 mm Body [DFN]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



#### RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	0.50 BSC		
Optional Center Pad Width	W2			1.45
Optional Center Pad Length	T2			1.75
Contact Pad Spacing	C1		2.90	
Contact Pad Width (X8)	X1			0.30
Contact Pad Length (X8)	Y1			0.75
Distance Between Pads	G	0.20		

#### Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2123A

NOTES:

#### APPENDIX A: REVISION HISTORY

#### **Revision C (February 2011)**

The following is the list of modifications:

- 1. Added the 8-lead, 2x3 DFN package and related information throughout the document.
- 2. Updated the package marking information and drawings.
- 3. Updated the Product Identification System page.

#### **Revision B (July 2010)**

The following is the list of modifications:

1. Updated the packaging specification.

#### Revision A (May 2010)

• Original Release of this Document.

NOTES:

#### **PRODUCT IDENTIFICATION SYSTEM**

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	× ×	<u>/xx</u>	Exa	amples:	
Device	Tape Temperature and Reel Range	Package	a)	MCP1623-I/CHY:	0.65V, Sync Reg., 6LD SOT-23 package
Device:	MCP1623: 0.65V, PWI Sync Boost	/ Only True Disconnect,	b)	MCP1623T-I/CHY:	Tape and Reel, 0.65V, Sync Reg., 6LD SOT-23 package
	MCP1623T: 0.65V, PWN Sync Boost	/ Only True Disconnect, Regulator (Tape and Reel)	c)	MCP1624-I/CHY:	0.65V, Sync Reg., 6LD SOT-23 package
	Sync Boost MCP1624T: 0.65V, PWN	//PFM True Disconnect, Regulator //PFM True Disconnect, Regulator (Tape and Reel)	d)	MCP1624T-I/CHY:	Tape and Reel, 0.65V, Sync Reg., 6LD SOT-23 package
Temperature	I = -40°C to +85°C (I	ndustrial)	e)	MCP1623-I/MC:	0.65V, Sync Reg., 8LD DFN package
Range: Package:	CHY = Plastic Small Out	ine Transistor (SOT-23), 6-lead	f)	MCP1623T-I/MC:	Tape and Reel, 0.65V, Sync Reg., 8LD DFN package
i donago.		No Lead Package (DFN 2x3) 8-lead	g)	MCP1624-I/MC:	0.65V, Sync Reg., 8LD DFN package
L			h)	MCP1624T-I/MC:	Tape and Reel, 0.65V, Sync Reg., 8LD DFN package

NOTES:

#### Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

### QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV ISO/TS 16949:2002

#### Trademarks

The Microchip name and logo, the Microchip logo, dsPIC, KEELOQ, KEELOQ logo, MPLAB, PIC, PICmicro, PICSTART, PIC<sup>32</sup> logo, rfPIC and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

FilterLab, Hampshire, HI-TECH C, Linear Active Thermistor, MXDEV, MXLAB, SEEVAL and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Analog-for-the-Digital Age, Application Maestro, CodeGuard, dsPICDEM, dsPICDEM.net, dsPICworks, dsSPEAK, ECAN, ECONOMONITOR, FanSense, HI-TIDE, In-Circuit Serial Programming, ICSP, Mindi, MiWi, MPASM, MPLAB Certified logo, MPLIB, MPLINK, mTouch, Omniscient Code Generation, PICC, PICC-18, PICDEM, PICDEM.net, PICkit, PICtail, REAL ICE, rfLAB, Select Mode, Total Endurance, TSHARC, UniWinDriver, WiperLock and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

All other trademarks mentioned herein are property of their respective companies.

© 2011, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

Printed on recycled paper.

ISBN: 978-1-60932-924-2

Microchip received ISO/TS-16949:2002 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



### **Worldwide Sales and Service**

#### AMERICAS

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: http://www.microchip.com/ support

Web Address: www.microchip.com

Atlanta Duluth, GA Tel: 678-957-9614 Fax: 678-957-1455

Boston Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL Tel: 630-285-0071 Fax: 630-285-0075

**Cleveland** Independence, OH Tel: 216-447-0464 Fax: 216-447-0643

**Dallas** Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit Farmington Hills, MI Tel: 248-538-2250 Fax: 248-538-2260

Indianapolis Noblesville, IN Tel: 317-773-8323 Fax: 317-773-5453

Los Angeles Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608

Santa Clara Santa Clara, CA Tel: 408-961-6444 Fax: 408-961-6445

Toronto Mississauga, Ontario, Canada Tel: 905-673-0699 Fax: 905-673-6509

#### ASIA/PACIFIC

Asia Pacific Office Suites 3707-14, 37th Floor Tower 6, The Gateway Harbour City, Kowloon Hong Kong Tel: 852-2401-1200 Fax: 852-2401-3431 Australia - Sydney

Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

**China - Beijing** Tel: 86-10-8528-2100 Fax: 86-10-8528-2104

**China - Chengdu** Tel: 86-28-8665-5511 Fax: 86-28-8665-7889

**China - Chongqing** Tel: 86-23-8980-9588 Fax: 86-23-8980-9500

**China - Hong Kong SAR** Tel: 852-2401-1200 Fax: 852-2401-3431

**China - Nanjing** Tel: 86-25-8473-2460 Fax: 86-25-8473-2470

**China - Qingdao** Tel: 86-532-8502-7355 Fax: 86-532-8502-7205

**China - Shanghai** Tel: 86-21-5407-5533 Fax: 86-21-5407-5066

China - Shenyang Tel: 86-24-2334-2829 Fax: 86-24-2334-2393

**China - Shenzhen** Tel: 86-755-8203-2660 Fax: 86-755-8203-1760

**China - Wuhan** Tel: 86-27-5980-5300 Fax: 86-27-5980-5118

**China - Xian** Tel: 86-29-8833-7252 Fax: 86-29-8833-7256

**China - Xiamen** Tel: 86-592-2388138 Fax: 86-592-2388130

**China - Zhuhai** Tel: 86-756-3210040 Fax: 86-756-3210049

#### ASIA/PACIFIC

India - Bangalore Tel: 91-80-3090-4444 Fax: 91-80-3090-4123

**India - New Delhi** Tel: 91-11-4160-8631 Fax: 91-11-4160-8632

India - Pune Tel: 91-20-2566-1512 Fax: 91-20-2566-1513

**Japan - Yokohama** Tel: 81-45-471- 6166 Fax: 81-45-471-6122

**Korea - Daegu** Tel: 82-53-744-4301 Fax: 82-53-744-4302

Korea - Seoul Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934

Malaysia - Kuala Lumpur Tel: 60-3-6201-9857 Fax: 60-3-6201-9859

**Malaysia - Penang** Tel: 60-4-227-8870 Fax: 60-4-227-4068

Philippines - Manila Tel: 63-2-634-9065 Fax: 63-2-634-9069

Singapore Tel: 65-6334-8870 Fax: 65-6334-8850

**Taiwan - Hsin Chu** Tel: 886-3-6578-300 Fax: 886-3-6578-370

**Taiwan - Kaohsiung** Tel: 886-7-213-7830 Fax: 886-7-330-9305

**Taiwan - Taipei** Tel: 886-2-2500-6610 Fax: 886-2-2508-0102

**Thailand - Bangkok** Tel: 66-2-694-1351 Fax: 66-2-694-1350

#### EUROPE

Austria - Wels Tel: 43-7242-2244-39 Fax: 43-7242-2244-393 Denmark - Copenhagen Tel: 45-4450-2828 Fax: 45-4485-2829

**France - Paris** Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

**Germany - Munich** Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

**Italy - Milan** Tel: 39-0331-742611 Fax: 39-0331-466781

Netherlands - Drunen Tel: 31-416-690399 Fax: 31-416-690340

**Spain - Madrid** Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

**UK - Wokingham** Tel: 44-118-921-5869 Fax: 44-118-921-5820

### **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Microchip: MCP1624T-I/CHY MCP1623-I/MC MCP1623T-I/MC